

UNISONIC TECHNOLOGIES CO., LTD

80N07 Preliminary Power MOSFET

80A, 70V N-CHANNEL POWER MOSFET

■ DESCRIPTION

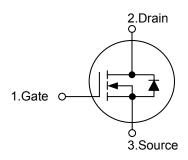
The UTC **80N07** is an N-channel MOSFET using UTC advanced technology.

The UTC **80N07** is suitable for power supply (secondary synchronous rectification), industrial and primary switch etc.



* $R_{DS(ON)}$ < 15m Ω @ V_{GS} = 10 V, I_{D} = 40 A

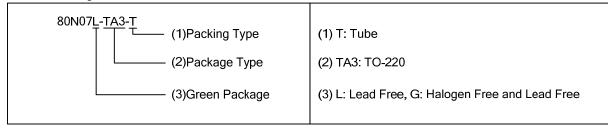
■ SYMBOL



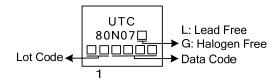
ORDERING INFORMATION

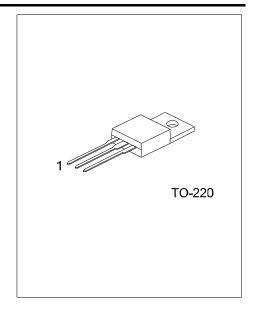
Ordering Number		Dookogo	Pin Assignment			Doolsing	
Lead Free	Halogen Free	Package	1	2	3	Packing	
80N07L-TA3-T	80N07G-TA3-T	TO-220	G	D	S	Tube	

Note: Pin Assignment: G: Gate D: Drain S: Source



■ MARKING





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■ ABSOLUTE MAXIMUM RATINGS (T_C=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DSS}	70	V
Gate-Source Voltage		V_{GSS}	±20	V
Continuous Drain Current	Continuous	I_{D}	80	Α
Pulsed Drain Current	Pulsed (Note 2)	I _{DM}	320	Α
Avalanche Current (Note 3)		I_{AR}	10	Α
Avalanche energy	Single Pulsed (Note 3)	E _{AS}	5.0	mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	5.5	V/nS
Power Dissipation		P_D	230	W
Junction Temperature		T _J	+150	°C
Storage Temperature Range		T_{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 3. L=0.1mH, I_{AS} =10A, V_{DD} =50V, R_{G} =25 Ω , Starting T_{J} = 25 $^{\circ}$ C.
- 4. $I_{SD} \le 30A$, di/dt $\le 200A/\mu s$, $V_{DD} \le V_{(BR)DSS}$, $T_J = 25$ °C.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	θ_{JA}	62.5	°C/W	
Junction to Case	θ_{JC}	0.54	°C/W	

■ ELECTRICAL CHARACTERISTICS (T_J =25°C, unless otherwise specified)

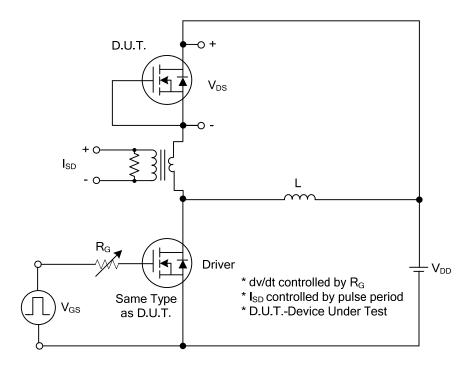
PARAMETER	SYMBOL	TEST CONDITIONS		TYP	MAX	UNIT		
OFF CHARACTERISTICS								
Drain-Source Breakdown Voltage	BV _{DSS}	I _D =250μA, V _{GS} =0V				V		
Drain-Source Leakage Current	I _{DSS}	V _{DS} =70V, V _{GS} =0V			1	μΑ		
Gate-Source Leakage Current	I_{GSS}	V_{DS} =0V, V_{GS} =±20V			±100	nA		
ON CHARACTERISTICS								
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2.0		4.0	V		
Static Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =40A			15	mΩ		
DYNAMIC PARAMETERS								
Input Capacitance	C_{ISS}			5480		pF		
Output Capacitance	Coss	V_{GS} =0V, V_{DS} =25V, f=1.0MHz		405		pF		
Reverse Transfer Capacitance	C_{RSS}	7		313		pF		
SWITCHING PARAMETERS								
Total Gate Charge (Note 1)	Q_G	V _{DS} =50V, V _{GS} =10V, I _D =1.3A, -I _D =100μA (Note 1, 2)		390		nC		
Gate to Source Charge	Q_GS			64		nC		
Gate to Drain Charge	Q_GD			90		nC		
Turn-on Delay Time (Note 1)	$t_{D(ON)}$			334		ns		
Rise Time	t_R	V_{DS} =30V, V_{GS} =10V, I_{D} =0.5A,		415		ns		
Turn-off Delay Time	t _{D(OFF)}	R _G =25Ω (Note 1, 2)		880		ns		
Fall-Time	t _F			370		ns		
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS								
Maximum Body-Diode Continuous Current	I_S				80	Α		
Maximum Body-Diode Pulsed Current	I _{SM}				320	Α		
Drain-Source Diode Forward Voltage (Note 1)	V_{SD}	I _S =80A, V _{GS} =0V			1.2	V		
Reverse Recovery Time (Note 1)	t _{rr}	I _S =30A, V _{GS} =0V,		60		ns		
Reverse Recovery Charge	Q_{rr}	dI _F /dt=100A/µs		70		nC		

Notes: 1. Pulse Test : Pulse width ≤ 300µs, Duty cycle ≤ 2%.

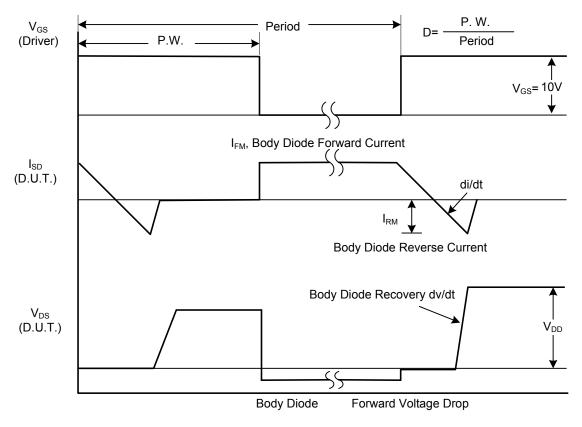
2. Essentially independent of operating temperature.



■ TEST CIRCUITS AND WAVEFORMS

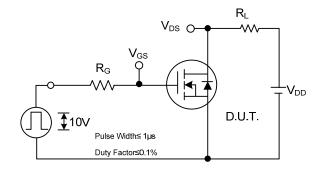


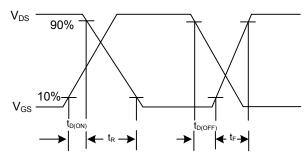
Peak Diode Recovery dv/dt Test Circuit



Peak Diode Recovery dv/dt Waveforms

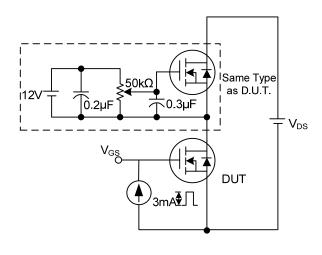
■ TEST CIRCUITS AND WAVEFORMS (Cont.)

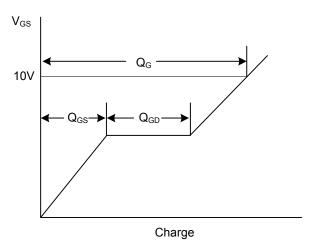




Switching Test Circuit

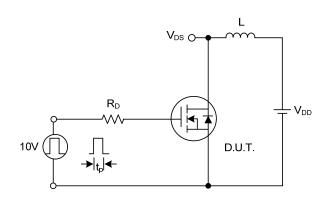
Switching Waveforms

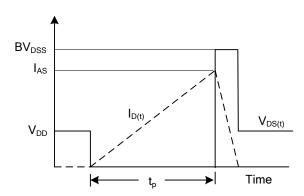




Gate Charge Test Circuit

Gate Charge Waveform





Unclamped Inductive Switching Test Circuit

Unclamped Inductive Switching Waveforms

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